## NSN 5961-00-052-9656

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View Online at https://aerobasegroup.com/nsn/5961-00-052-9656

## **Inclosure Material:**

Metal

**Overall Length:** 

0.802 inches

## **Terminal Length:**

1.500 inches

## **Mounting Facility Quantity:**

1

## Internal Configuration:

Junction contact

## Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-13

#### Mounting Method:

Terminal and threaded stud

## Terminal Circle Diameter:

0.200 inches

## Features Provided:

Hermetically sealed case

## **Overall Width Across Flats:**

0.442 inches

## Thread Size:

0.190 inches

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

150.0 breakdown voltage, collector-to-base, emitter open and 6.0 emitter to base voltage, static, collector open and 100.0 breakdown voltage, collector-to-emitter, base open

#### **Current Rating Per Characteristic:**

750.00 milliamperes repetitive peak forward current blank and 750.00 milliamperes repetitive peak forward current

#### **Power Rating Per Characteristic:**

2.0 watts small-signal input power, common-collector

#### **Transfer Ratio:**

20.0 static forward current transfer ratio, common-emitter and 60.0 static forward current transfer ratio, common-emitter

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Thread Series Designator:**

Unf

#### Terminal Type And Quantity:

2 uninsulated wire lead and 1 threaded stud

#### Shelf Life:

N/a

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Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

